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2. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		_
2	d	drain	mb	
3	S	source		
mb	D	mounting base; connected to drain		mbb076 S
			SOT428 (DPAK)	

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BUK7219-55A	DPAK	plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped)	SOT428

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

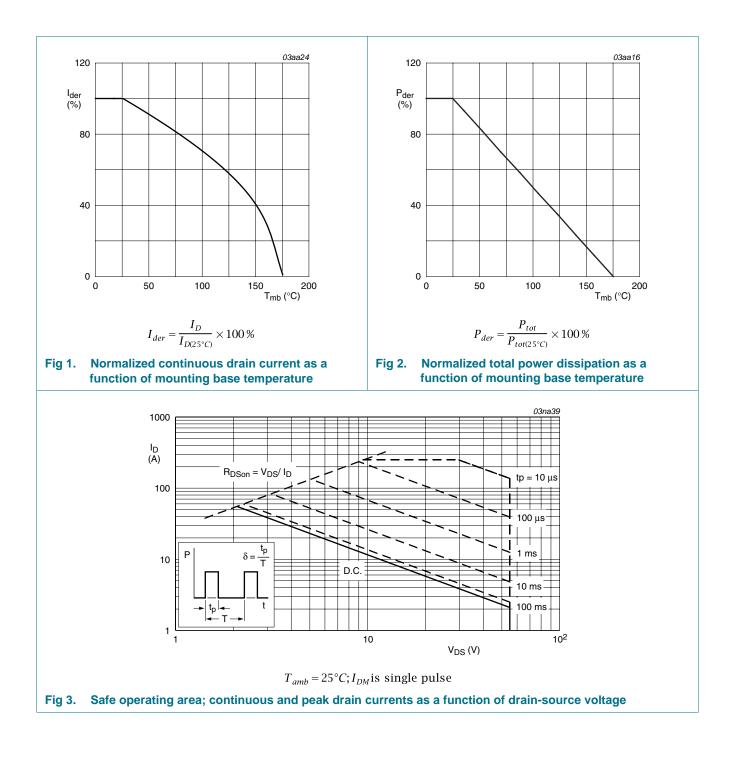
Symbol	Parameter	Conditions		Min	Мах	Unit
V _{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C		-	55	V
V _{DGR}	drain-gate voltage	$R_{GS} = 20 \ k\Omega$		-	55	V
V _{GS}	gate-source voltage			-20	20	V
I _D	drain current	T_{mb} = 100 °C; V_{GS} = 5 V; see <u>Figure 1</u>		-	39	А
		T_{mb} = 25 °C; V_{GS} = 5 V; see <u>Figure 1</u> and <u>3</u>		-	55	А
I _{DM}	peak drain current	T_{mb} = 25 °C; $t_p \le 10 \ \mu$ s; pulsed; see Figure 3	<u>[1]</u>	-	250	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; see <u>Figure 2</u>		-	114	W
T _{stg}	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
Avalanch	e ruggedness					
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	$ I_D = 49 \text{ A}; \text{V}_{\text{sup}} \leq 55 \text{ V}; \text{R}_{\text{GS}} = 50 \Omega; \text{V}_{\text{GS}} = 10 \text{ V}; \\ \text{T}_{j(\text{init})} = 25 ^{\circ}\text{C}; \text{ unclamped} $		-	120	mJ
Source-dr	rain diode					
I _S	source current	T _{mb} = 25 °C		-	55	А
I _{SM}	peak source current	$t_p \le 10 \ \mu s$; pulsed; $T_{mb} = 25 \ ^{\circ}C$		-	250	А

[1] Peak drain current is limited by chip, not package.

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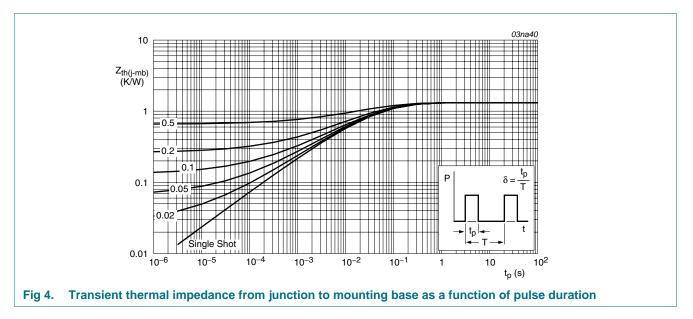
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5. Thermal characteristics

Table 5.	Thermal characteristics							
Symbol	Parameter	Conditions	Min	Тур	Max	Unit		
R _{th(j-mb)}	thermal resistance from junction to mounting base		-	-	1.3	K/W		
R _{th(j-a)}	thermal resistance from junction to ambient	see Figure 4	-	71.4	-	K/W		



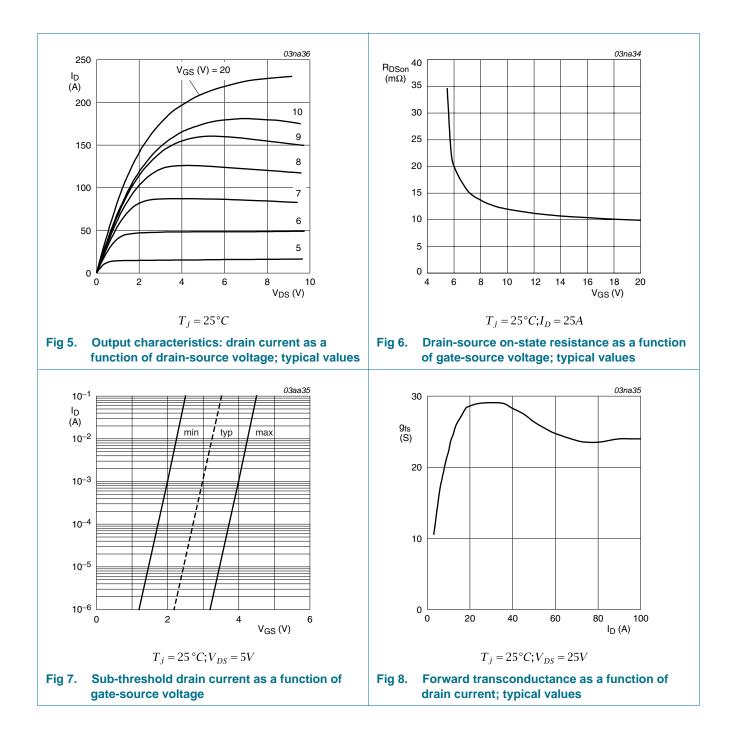
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6. Characteristics

Table 6.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
V _{(BR)DSS}	drain-source	$I_D = 0.25 \text{ mA}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$	55	-	-	V
	breakdown voltage	$I_D = 0.25 \text{ mA}; V_{GS} = 0 \text{ V}; T_j = -55 \text{ °C}$	50	-	-	V
V _{GS(th)}	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C};$ see <u>Figure 11</u>	2	3	4	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C};$ see <u>Figure 11</u>	-	-	4.4	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 175 \text{ °C};$ see <u>Figure 11</u>	1	-	-	V
I _{DSS}	drain leakage current	$V_{DS} = 55 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	0.05	10	μA
		$V_{DS} = 55 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 175 \text{ °C}$	-	-	500	μA
I _{GSS}	gate leakage current	$V_{DS} = 0 \text{ V}; V_{GS} = 10 \text{ V}; T_j = 25 \text{ °C}$	-	2	100	nA
		$V_{DS} = 0 \text{ V}; V_{GS} = -10 \text{ V}; T_j = 25 \text{ °C}$	-	2	100	nA
R _{DSon}	drain-source on-state resistance	V_{GS} = 10 V; I_D = 25 A; T_j = 175 °C; see <u>Figure 12</u> and <u>13</u>	-	-	38	mΩ
		V_{GS} = 10 V; I _D = 25 A; T _j = 25 °C; see <u>Figure 12</u> and <u>13</u>	-	16	19	mΩ
Dynamic	characteristics					
C _{iss}	input capacitance	$V_{GS} = 0 V; V_{DS} = 25 V; f = 1 MHz;$	-	1581	2108	pF
C _{oss}	output capacitance	$T_j = 25 \text{ °C}; \text{ see } Figure 15$	-	372	446	pF
C _{rss}	reverse transfer capacitance		-	221	303	pF
t _{d(on)}	turn-on delay time	$V_{DS} = 30 \text{ V}; \text{ R}_{L} = 1.2 \Omega; \text{ V}_{GS} = 5 \text{ V};$	-	16	-	ns
t _r	rise time	$R_{G(ext)} = 10 \ \Omega; T_j = 25 \ ^{\circ}C$	-	70	-	ns
t _{d(off)}	turn-off delay time		-	57	-	ns
t _f	fall time		-	41	-	ns
L _D	internal drain inductance	measured from drain lead from package to centre of die; $T_j = 25 \text{ °C}$	-	2.5	-	nH
L _S	internal source inductance	measured from source lead from package to source bond pad; T _j = 25 °C	-	7.5	-	nH
Source-d	rain diode					
V _{SD}	source-drain voltage	I _S = 25 A; V _{GS} = 0 V; T _j = 25 °C; see <u>Figure 14</u>	-	0.85	1.2	V
t _{rr}	reverse recovery time	$I_S = 25 \text{ A}; \text{ dI}_S/\text{dt} = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = -10 \text{ V};$ $V_{DS} = 30 \text{ V}; \text{ T}_j = 25 \ ^{\circ}\text{C}$	-	48	-	ns
Q _r	recovered charge		-	106	-	nC

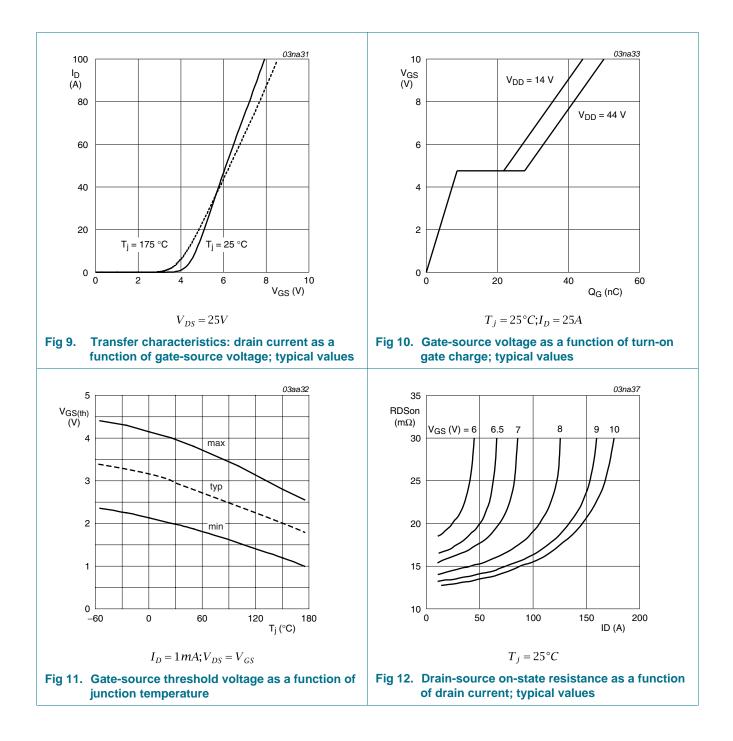
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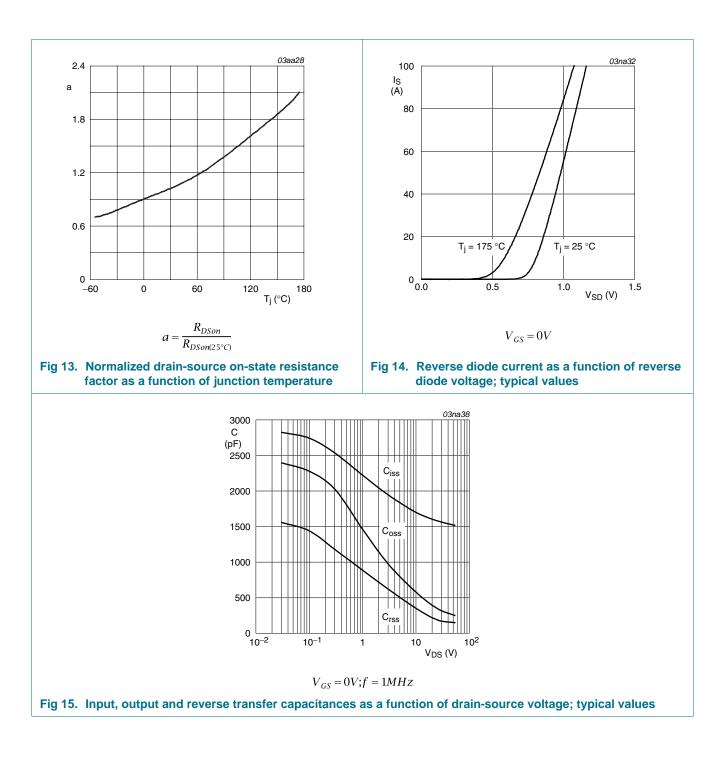
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7. Package outline

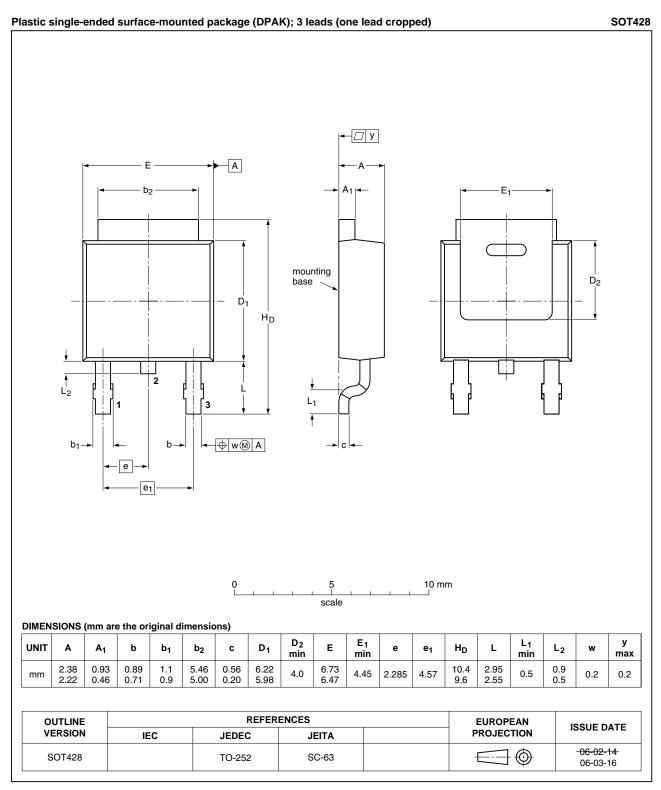


Fig 16. Package outline SOT428 (DPAK)

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8. Revision history

Table 7. Revision his	tory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
BUK7219-55A_2	20100203	Product data sheet	-	BUK7219-55A-01
Modifications:		t of this data sheet has be of NXP Semiconductors.	• .	y with the new identity
	 Legal texts 	have been adapted to the	ne new company name v	vhere appropriate.
BUK7219-55A-01 (9397 750 07575)	20001002	Product specification	-	-

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9. Legal information

9.1 Data sheet status

Document status [1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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